NSN 5961-01-229-6882

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-229-6882 **Inclosure Material:** Metal **Overall Length:** 0.550 inches Overall Diameter: 0.487 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.500 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 reverse voltage, average and 100.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 12.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Specification Data:** 81349-mil-s-19500/304 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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